Low-ohmic single-pole double-throw analog switch

Rev. 7.1 — 15 November 2016

Product data sheet

1. General description

The NX3L1G53 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1), a common input/output (Z) and an active LOW enable input (\overline{E}). When pin \overline{E} is HIGH, the switch is turned off. Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times.

The NX3L1G53 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y0 or Y1; or from Y0 or Y1 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C



3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

Type number	Package	Package							
	Temperature range	Name	Description	Version					
NX3L1G53GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1					
NX3L1G53GD	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm	SOT996-2					
NX3L1G53GM	–40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5$ mm	SOT902-2					

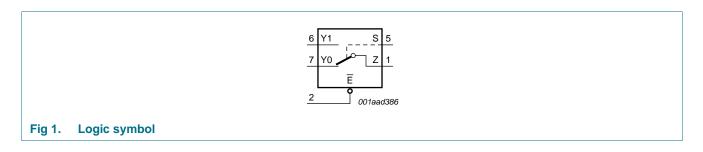
5. Marking

Table 2. Marking codes^[1]

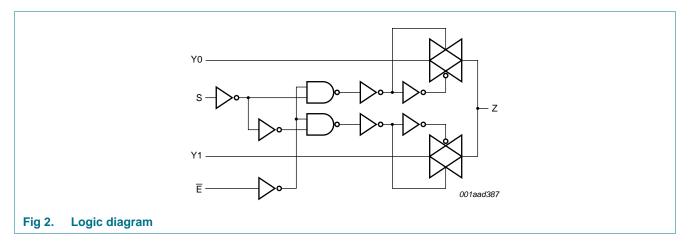
Type number	Marking code
NX3L1G53GT	D53
NX3L1G53GD	D53
NX3L1G53GM	D53

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram

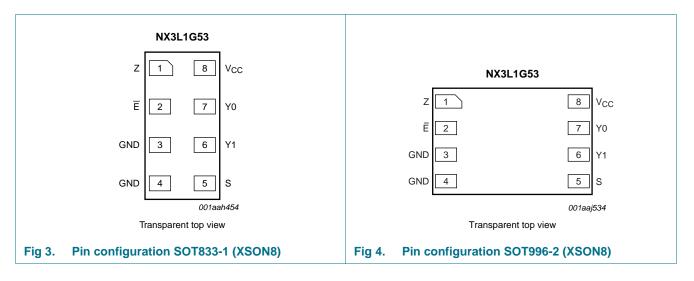


Low-ohmic single-pole double-throw analog switch



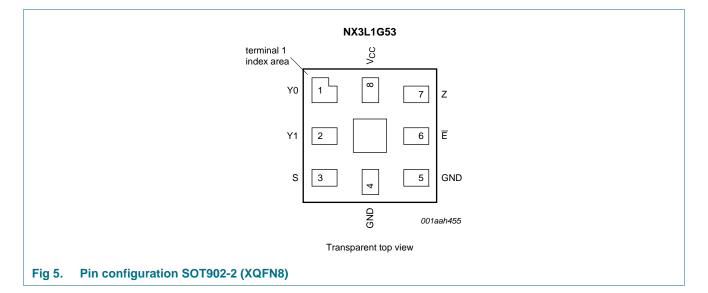
7. Pinning information

7.1 Pinning



NX3L1G53

Low-ohmic single-pole double-throw analog switch



7.2 Pin description

Table 3.	Pin description		
Symbol	Pin		Description
	SOT833-1 and SOT996-2	SOT902-2	
Z	1	7	common output or input
E	2	6	enable input (active LOW)
GND	3	5	ground (0 V)
GND	4	4	ground (0 V)
S	5	3	select input
Y1	6	2	independent input or output
Y0	7	1	independent input or output
V _{CC}	8	8	supply voltage

8. Functional description

Table 4.Function table

Input	Channel	
S	Ē	
L	L	Y0 to Z or Z to Y0
Н	L	Y1 to Z or Z to Y1
Х	Н	switch off

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

NX3L1G53 Product data sheet

4 of 24

Low-ohmic single-pole double-throw analog switch

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S and enable input \overline{E}	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		[2] _0.5	V _{CC} + 0.5	V
I _{IK}	input clamping current	$V_{l} < -0.5 V$	-50	-	mA
I _{SK}	switch clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V _{SW} > -0.5 V or V _{SW} < V _{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S and enable input \overline{E}	0	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	V _{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.4 V to 4.3 V	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signals.

11. Static characteristics

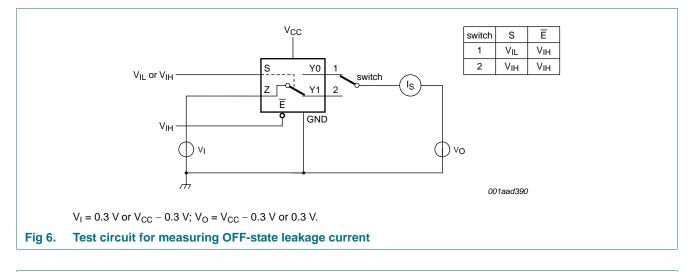
Table 7. Static characteristics

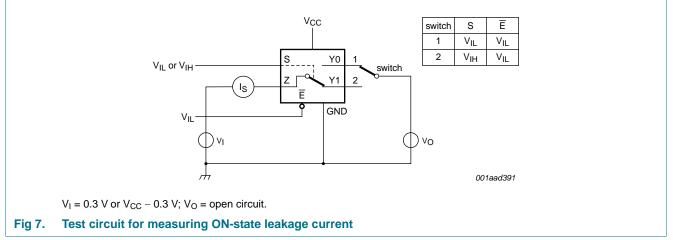
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C		
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V _{IH}	HIGH-level	$V_{CC} = 1.4 \text{ V}$ to 1.95 V	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	-	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
V _{IL}	LOW-level	V_{CC} = 1.4 V to 1.95 V	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	$0.35V_{CC}$	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	0.8	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
II	input leakage current	select input S and enable input \overline{E} ; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
$I_{S(OFF)}$	OFF-state leakage	Y0 and Y1 port; see <u>Figure 6</u>							
	current	V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	Z port; see Figure 7							
	leakage current	V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
	current	V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	130	-	-	-	-	pF

Low-ohmic single-pole double-throw analog switch

11.1 Test circuits





11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 9 to Figure 15.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	• +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Мах	
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see Figure 8						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_{I} = \text{GND to } V_{\text{CC}}; \qquad [2] \\ I_{\text{SW}} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V _{CC} = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_I = GND$ to V_{CC} ; [3] $I_{SW} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

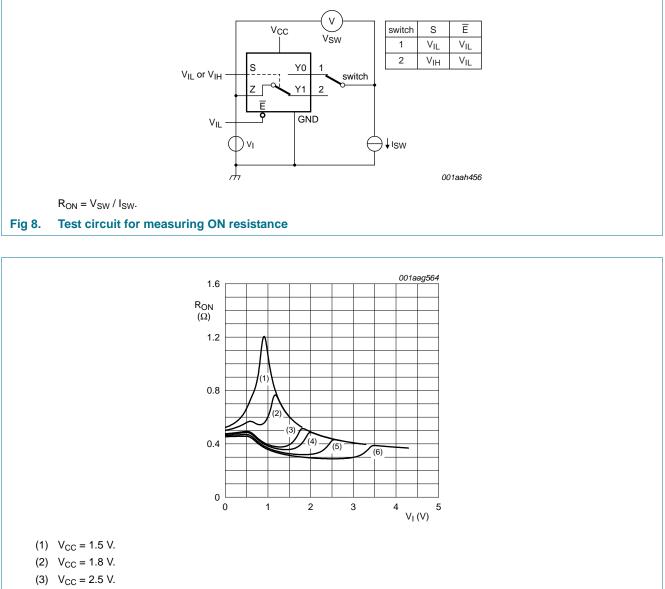
[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] Measured at identical V_{CC}, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

Low-ohmic single-pole double-throw analog switch

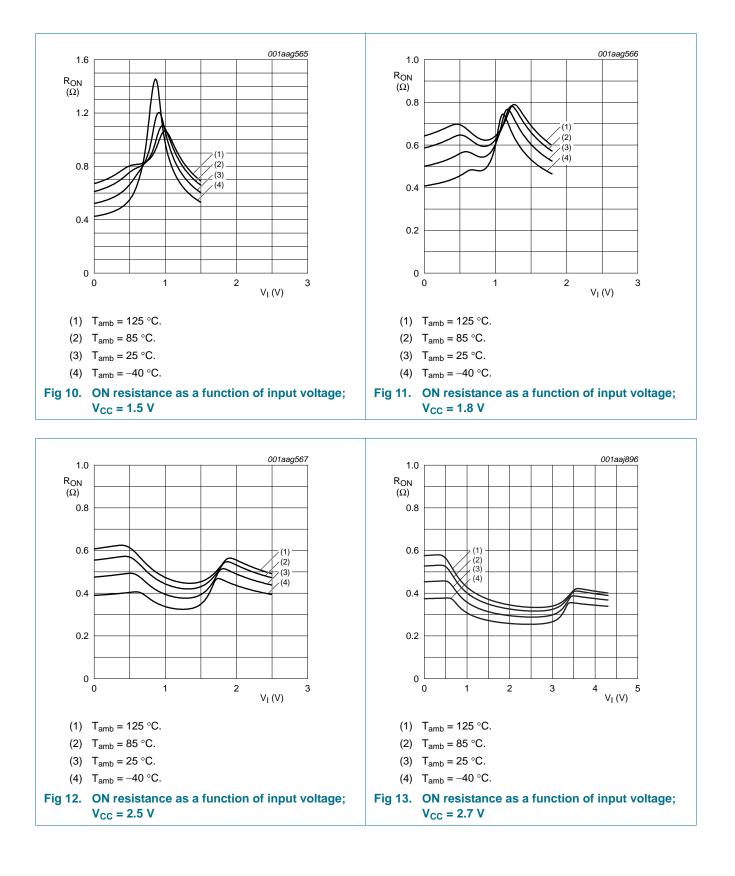
11.3 ON resistance test circuit and waveforms



- (4) $V_{CC} = 2.7 V.$
- (5) $V_{CC} = 3.3 V.$ (6) $V_{CC} = 4.3$ V.
 - Measured at $T_{amb} = 25 \ ^{\circ}C$.
- Fig 9. ON resistance as a function of input voltage

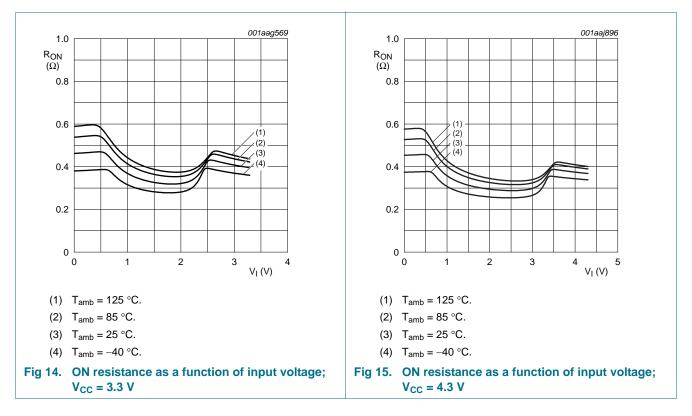
NX3L1G53

Low-ohmic single-pole double-throw analog switch



NX3L1G53

Low-ohmic single-pole double-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 18.

Symbol	Parameter	Conditions		25 °C		-40	°C to +12	5 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	S or E to Z or Yn; see <u>Figure 16</u>							
		V_{CC} = 1.4 V to 1.6 V	-	28	42	-	45	50	ns
		V _{CC} = 1.65 V to 1.95 V	-	23	34	-	37	41	ns
		V_{CC} = 2.3 V to 2.7 V	-	17	27	-	29	31	ns
		V_{CC} = 2.7 V to 3.6 V	-	15	24	-	26	28	ns
		V_{CC} = 3.6 V to 4.3 V	-	15	24	-	26	28	ns
t _{dis}	disable time	S or Ē to Z or Yn; see <u>Figure 16</u>							
		V_{CC} = 1.4 V to 1.6 V	-	10	19	-	21	23	ns
		V_{CC} = 1.65 V to 1.95 V	-	7	14	-	16	17	ns
		V_{CC} = 2.3 V to 2.7 V	-	5	9	-	10	11	ns
		V_{CC} = 2.7 V to 3.6 V	-	4	8	-	9	9	ns
		V_{CC} = 2.7 V to 4.3 V	-	4	8	-	9	9	ns

11 of 24

Low-ohmic single-pole double-throw analog switch

Symbol	Parameter Conditions 25 °C		–40 °C to +125 °C			Unit				
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t _{b-m}	break-before-make	see Figure 17	[2]							
time	time	V_{CC} = 1.4 V to 1.6 V		-	19	-	9	-	-	ns
		V_{CC} = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		V_{CC} = 2.3 V to 2.7 V		-	13	-	5	-	-	ns
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$		-	10	-	3	-	-	ns
		V_{CC} = 2.7 V to 4.3 V		-	10	-	2	-	-	ns

Table 9. Dynamic characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 18.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

12.1 Waveform and test circuits

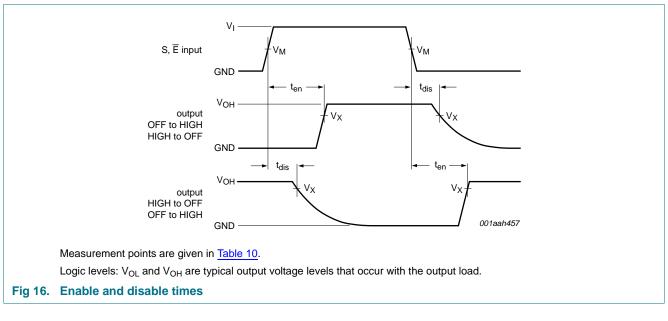
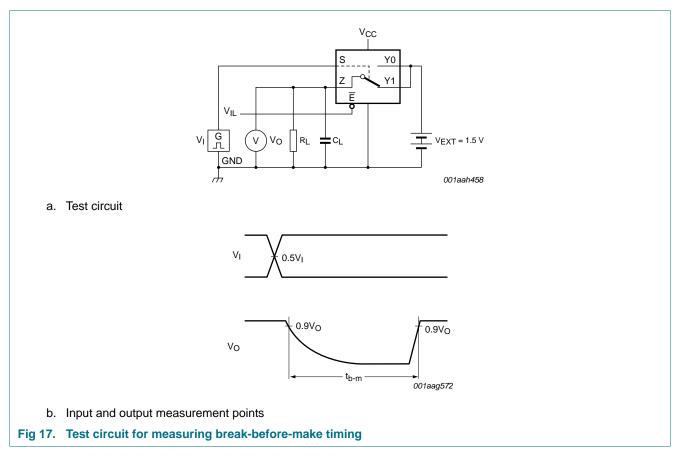


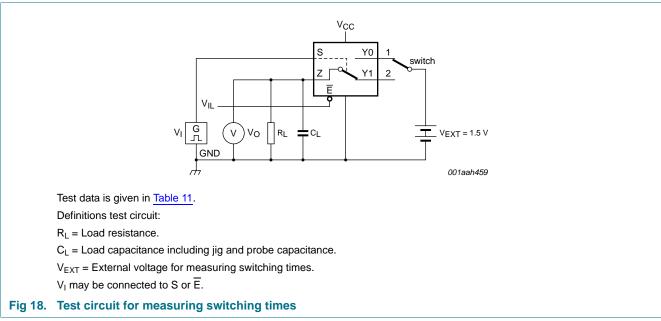
Table 10. Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

NX3L1G53

Low-ohmic single-pole double-throw analog switch





NX3L1G53

Table 11.Test data

Supply voltage	Input		Load	
V _{cc}	V _I t _r , t _f C		CL	RL
1.4 V to 4.3 V	V _{CC}	≤ 2.5 ns	35 pF	50 Ω

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

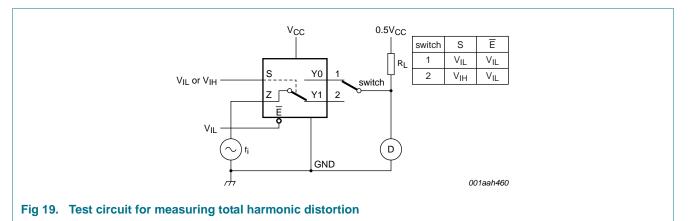
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

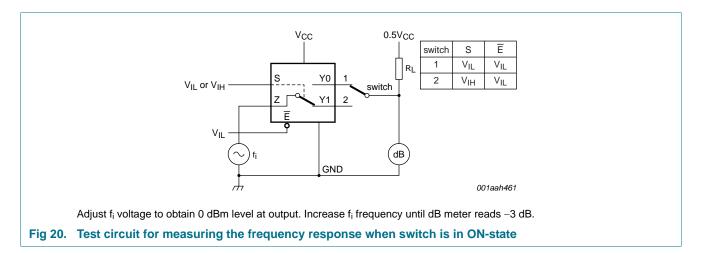
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
THD	total harmonic distortion	$f_i = 20 \text{ Hz to } 20 \text{ kHz}; \text{ R}_L = 32 \Omega; \text{ see } \frac{\text{Figure } 19}{1000 \text{ sec } 19}$	<u>[1]</u>			
		V _{CC} = 1.4 V; V _I = 1 V (p-p)	-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)	-	0.10	-	%
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)	-	0.02	-	%
		V _{CC} = 2.7 V; V _I = 2 V (p-p)	-	0.02	-	%
		V _{CC} = 4.3 V; V _I = 2 V (p-p)	-	0.02	-	%
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see <u>Figure 20</u>	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	60	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 21}}{100 \text{ kHz}}$	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 22				
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	0.3	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$; $R_L = 50 \Omega$; see <u>Figure 23</u>	[1]			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	-90	-	dB
Q _{inj}	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega;$ see <u>Figure 24</u>				
		$V_{CC} = 1.5 V$	-	3	-	рС
		V _{CC} = 1.8 V	-	4	-	рС
		$V_{CC} = 2.5 V$	-	6	-	рС
		$V_{CC} = 3.3 V$	-	9	-	рС
		$V_{CC} = 4.3 V$	-	15	-	рС

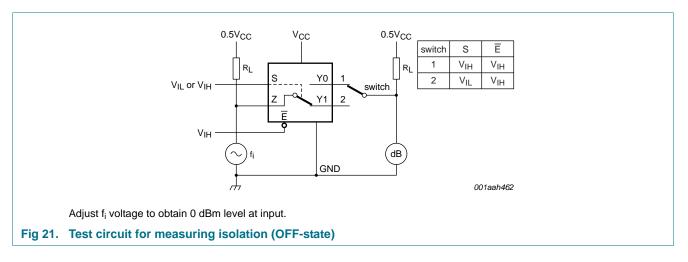
[1] f_i is biased at 0.5V_{CC}.

Low-ohmic single-pole double-throw analog switch

12.3 Test circuits



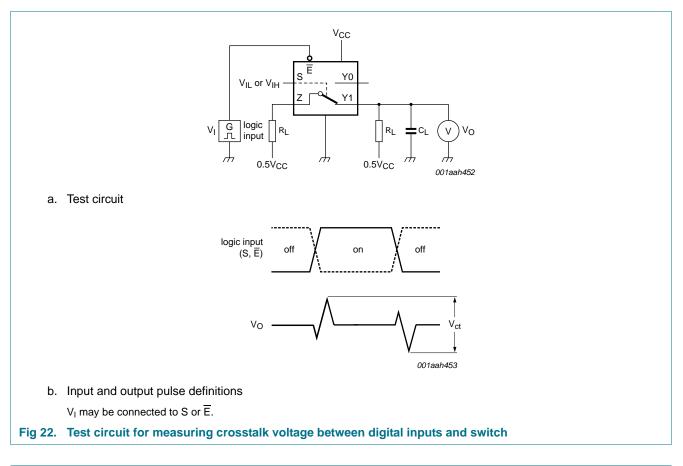


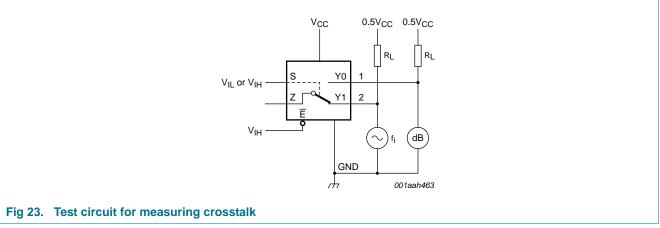


NX3L1G53

NX3L1G53

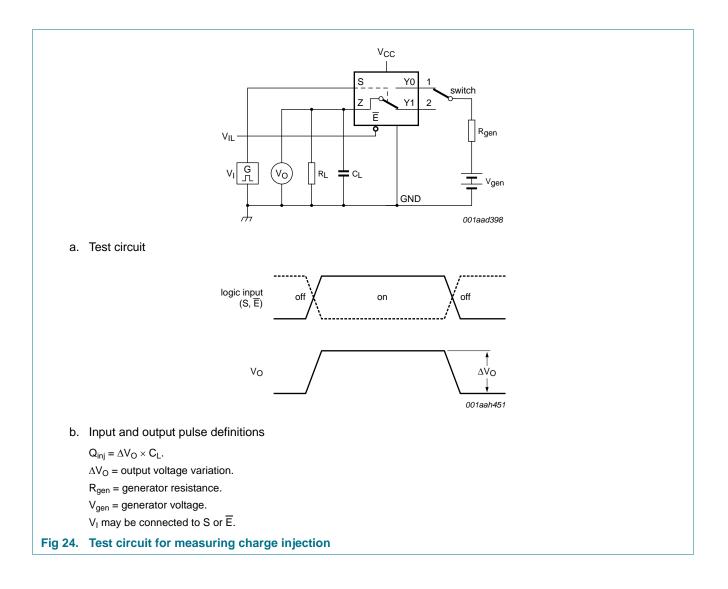
Low-ohmic single-pole double-throw analog switch





NX3L1G53

Low-ohmic single-pole double-throw analog switch



NX3L1G53 Product data sheet

Low-ohmic single-pole double-throw analog switch

13. Package outline

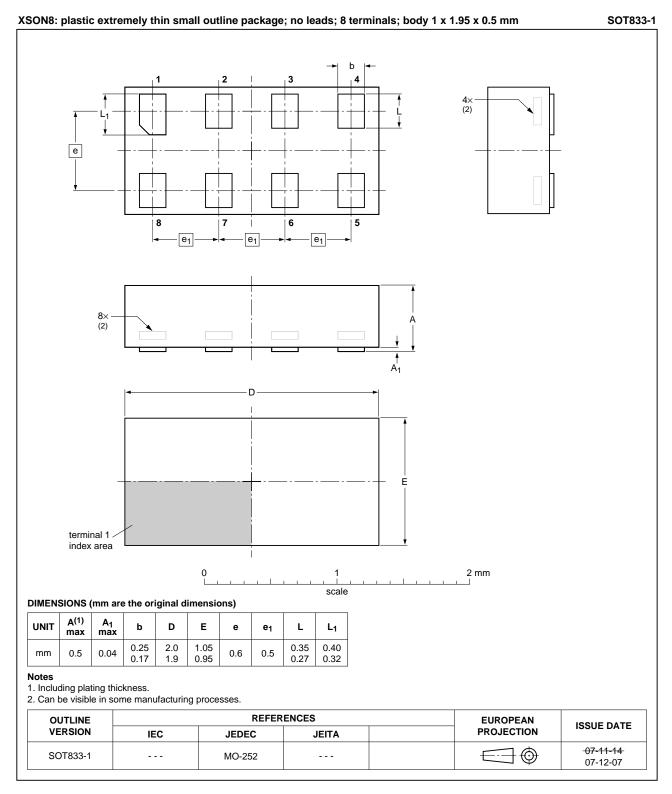
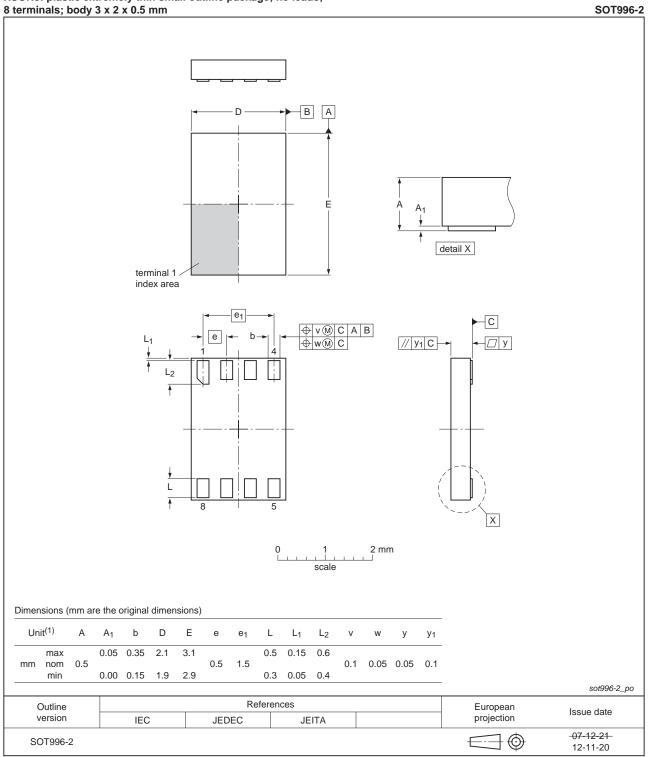


Fig 25. Package outline SOT833-1 (XSON8)

NX3L1G53 Product data sheet

Low-ohmic single-pole double-throw analog switch



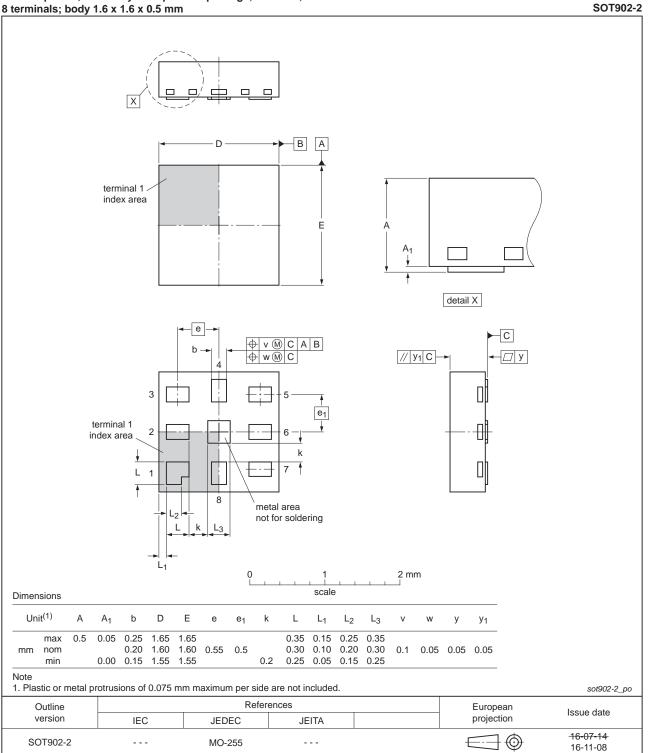
XSON8: plastic extremely thin small outline package; no leads;

Fig 26. Package outline SOT996-2 (XSON8)

All information provided in this document is subject to legal disclaimers.

NX3L1G53

Low-ohmic single-pole double-throw analog switch



XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm

Fig 27. Package outline SOT902-2 (XQFN8)

All information provided in this document is subject to legal disclaimers.

NX3L1G53

14. Abbreviations

Table 13.	Abbreviations		
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		
TTL	Transistor-Transistor Logic		

15. Revision history

Table 14. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1G53 v.7.1	20161115	Product data sheet	-	NX3L1G53 v.7
Modifications:	 Updated Fig 	gure 27 "Package outline S	OT902-2 (XQFN8)"	
NX3L1G53 v.7	20130208	Product data sheet	-	NX3L1G53 v.6
Modifications:	 For type null 	mber NX3L1G53GD XSON	8U has changed to XSO	N8
NX3L1G53 v.6	20120613	Product data sheet	-	NX3L1G53 v.5
NX3L1G53 v.5	20111109	Product data sheet	-	NX3L1G53 v.4
NX3L1G53 v.4	20100127	Product data sheet	-	NX3L1G53 v.3
NX3L1G53 v.3	20090417	Product data sheet	-	NX3L1G53 v.2
NX3L1G53 v.2	20080718	Product data sheet	-	NX3L1G53 v.1
NX3L1G53 v.1	20080408	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

NX3L1G53

© NXP B.V. 2016. All rights reserved.

Low-ohmic single-pole double-throw analog switch

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

NX3L1G53

23 of 24

Low-ohmic single-pole double-throw analog switch

18. Contents

1	General description	. 1
2	Features and benefits	. 1
3	Applications	. 2
4	Ordering information	. 2
5	Marking	. 2
6	Functional diagram	. 2
7	Pinning information	. 3
7.1	Pinning	. 3
7.2	Pin description	
8	Functional description	. 4
9	Limiting values	. 5
10	Recommended operating conditions	. 5
11	Static characteristics	. 6
11.1	Test circuits	. 7
11.2	ON resistance	. 8
11.3	ON resistance test circuit and waveforms	. 9
12	Dynamic characteristics	11
12.1	Waveform and test circuits	12
12.2	Additional dynamic characteristics	
12.3	Test circuits	-
13	Package outline	18
14	Abbreviations	21
15	Revision history	21
16	Legal information	22
16.1	Data sheet status	22
16.2	Definitions	22
16.3	Disclaimers	22
16.4	Trademarks	23
17	Contact information	23
18	Contents	24

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2016.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 15 November 2016 Document identifier: NX3L1G53

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP:

NX3L1G53GM,125 NX3L1G53GT,115 NX3L1G53GD,125